## 山东晶导微电子股份有限公司 Jingdao Microelectronics co.LTD MBR340xS THRU MBR3200xS

## SCHOTTKY BARRIER RECTIFIERS

Reverse Voltage - 40 to 200 V

Forward Current - 3.0 A

### FEATURES

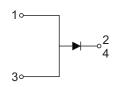
- High current capability
- Low forward voltage drop
- Low power loss, high efficiency
- High surge capability
- High temperature soldering guaranteed
- Mounting position: any

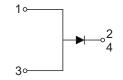


TO-252(D-PAK)









### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

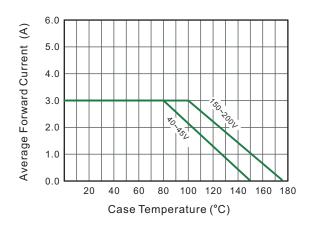
CHARACTERISTICS	TO-251	MBR340VS	MBR345VS	MBR360VS	MBR3100VS	MBR3150VS	MBR3200VS	Units				
	TO-252	MBR340DS	MBR345DS	MBR360DS	MBR3100DS	MBR3150DS	MBR3200DS	Units				
Maximum Recurrent Peak Reverse Voltage	$V_{\text{RRM}}$	40	45	60	100	150	200	V				
Maximum RMS voltage	$V_{\text{RMS}}$	28	31.5	42	70	105	140	V				
Maximum DC Blocking Voltage	V <sub>DC</sub>	40	45	60	100	150	200	V				
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>		3.0									
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub> 80											
Max Instantaneous Forward Voltage at 3 A	V <sub>F</sub>	0.	65	0.70	0.85	0.90	0.92	V				
Maximum DC Reverse Current T <sub>a</sub> = 25°C at Rated DC Reverse Voltage T <sub>a</sub> =125°C	I <sub>R</sub>		0.1 20		0.05 20	mA						
Typical Junction Capacitance <sup>(1)</sup>	Cj	600 400										
Typical Thermal Resistance <sup>(2)</sup>	Thermal Resistance <sup>(2)</sup> R <sub>BJA</sub> 45											
Operating Junction Temperature Range	Junction Temperature Range T <sub>j</sub> -55 ~ +150 -55 ~ +175											
Storage Temperature Range	T <sub>stg</sub>	-55 ~ +150 -55 ~ +175										

( 1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 10cmX10cmX1mm copper pad areas.

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#### Fig.1 TYPICAL FORWARD CURRENT DERATING CURVE



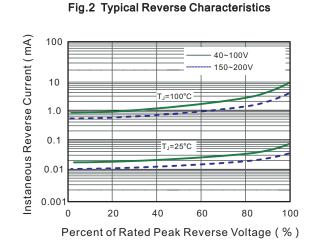


Fig.3 Typical Forward Characteristic

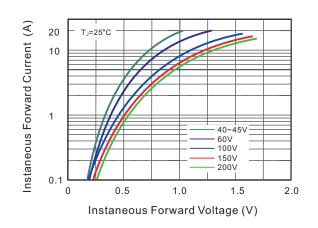
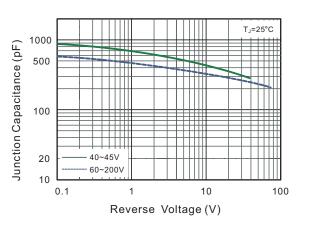


Fig.4 Typical Junction Capacitance



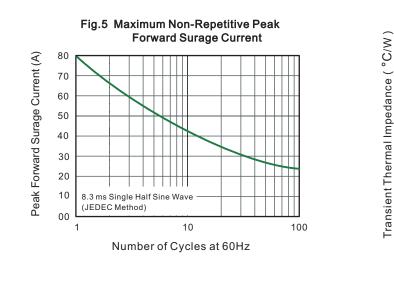
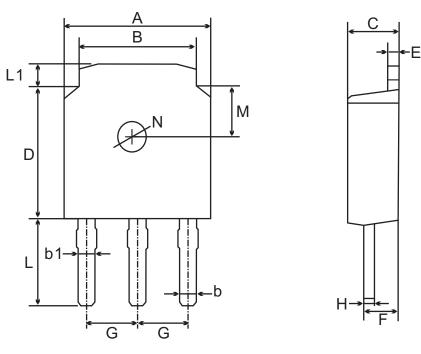


Fig.6- Typical Transient Thermal Impedance

## TO-251(D-PAK) Package Outline Dimensions



## TO-251(I-PAK) mechanical data

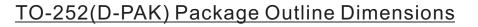
UN	IIT	А	В	b	b1	С	D	E	F	G	н	L	L1	М	Ν
	max	6.7	5.5	0.8	0.9	2.5	6.3	0.6	1.8	2.29	0.55	5 4.3 1.2		1.8	1.3
ım -	min	6.3	6.3 5.1 0.3 0.76 2.1 5.9 0.4 1.3	TYPICAL	0.45	3.9	0.8	TYPICAL	TYPICAL						
ail	max	264	217	31	35	98	248	24	71	90	22	169	47	71	51
mil -	min	248	201	12	30	83	232	16	51	TYPICAL	18	154 31		TYPICAL	TYPICAL

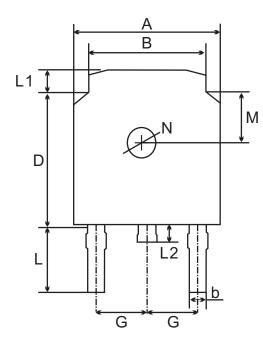
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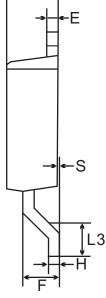
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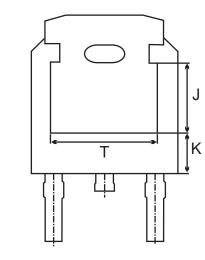
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TO-252(D-PAK) mechanical data

U	Π	А	В	b	С	D	Е	F	G	Н	L	L1	L2	L3	S	М	Ν	J	К	Т
mm	max	6.7	5.5	0.8	2.5	6.3	0.6	1.8	2.29	0.55	3.1	1.2	1.0	1.75	0.1	1.8 TYPICAL	-			4.83 ref.
	min	6.3	5.1	0.3	2.1	5.9	0.4	1.3	TYPICAL	0.45	2.7	0.8	0.6	1.40	0.0					
I	max	264	217	31	98	248	24	71	90	22	122	47	39	69	4	71	51	124	71	190
mil	min	248	201	12	83	232	16	51	TYPICAL	18	106	31	24	55	0	TYPICAL	TYPICAL	ref.	ref.	ref.

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